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Kind regards,

Team Nexperia

# 74HC4049

# Hex inverting HIGH-to-LOW level shifter

Rev. 7 — 5 February 2016

**Product data sheet** 

# 1. General description

The 74HC4049 is a hex inverter with over-voltage tolerant inputs. Inputs are overvoltage tolerant to 15 V. This enables the device to be used in HIGH-to-LOW level shifting applications.

### 2. Features and benefits

- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ♦ HBM JESD22-A114F exceeds 2 000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

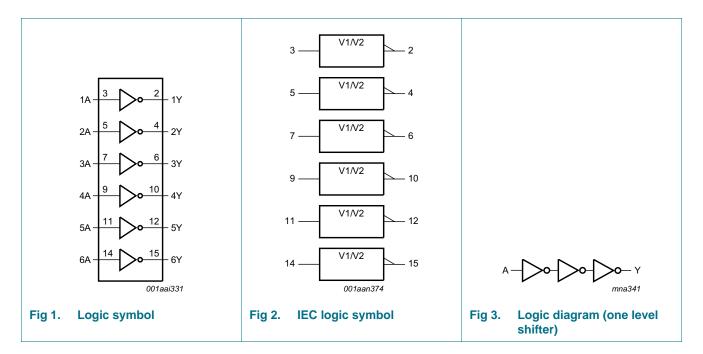
# 3. Ordering information

#### Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74HC4049D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
74HC4049DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1					
74HC4049PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					

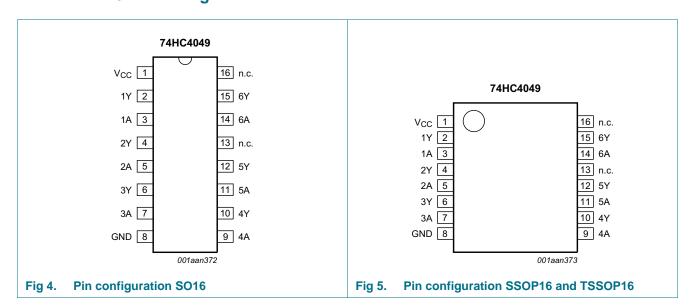


# 4. Functional diagram



# 5. Pinning information

## 5.1 Pinning



#### Hex inverting HIGH-to-LOW level shifter

### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
V <sub>CC</sub>	1	supply voltage
1Y to 6Y	2, 4, 6, 10, 12, 15	output
1A to 6A	3, 5, 7, 9, 11, 14	input
GND	8	ground (0 V)
n.c.	13, 16	not connected

# 6. Functional description

Table 3. Function table [1]

Input	Output
nA	nY
L	Н
Н	L

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

# 7. Limiting values

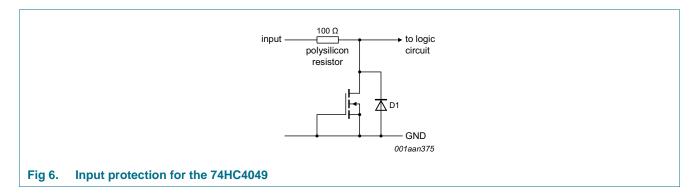
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7	V
$V_{IK}$	input clamping voltage			-0.5	+16	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V		-20	-	mA
I <sub>OK</sub>	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$		-	±25	mA
I <sub>CC</sub>	supply current			-	+50	mA
I <sub>GND</sub>	ground current			-	-50	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	SO16, SSOP16 and TSSOP16 packages	<u>[1]</u>	-	500	mW

<sup>[1]</sup> For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C. For SSOP16 and TSSOP16 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

#### Hex inverting HIGH-to-LOW level shifter



# 8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	15	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}; V_I = 2.0 \text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5 \text{ V}; V_I = 4.5 \text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 6.0 \text{ V}$	-	-	83	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 10.0 \text{ V}$	-	-	81	ns/V
İ		$V_{CC} = 6.0 \text{ V}; V_I = 15.0 \text{ V}$	-	-	83	ns/V

## 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.3	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.1	-	4.2	-	4.2	-	V
V <sub>IL</sub>	V <sub>IL</sub> LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.7	0.5	-	0.5	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	1.8	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.3	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V

74HC4049

#### Hex inverting HIGH-to-LOW level shifter

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Tai	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	-	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	-	0.1	-	0.1	-	0.1	V
	$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	-	0.1	-	0.1	-	0.1	V	
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
		$V_1 = 15 \text{ V}; V_{CC} = 2.0 \text{ V} \text{ to}$ 6.0 V	-	-	±0.5	-	±5.0	-	±5.0	μА
I <sub>CC</sub>	supply current	$V_I$ = 15 V or GND; $I_O$ = 0 A; $V_{CC}$ = 6.0 V	-	-	2.0	-	20	-	40	μА
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

# 10. Dynamic characteristics

#### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit see Figure 8.

Symbol Pa	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation	nA to nY; see Figure 7 [1]								
	delay	V <sub>CC</sub> = 2.0 V	-	28	85	-	105	-	130	ns
		V <sub>CC</sub> = 4.5 V	-	10	17	-	21	-	26	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	8	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	8	14	-	18	-	22	ns
t <sub>t</sub>	transition	Yn; see Figure 7 [2]								
	time	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns

#### Hex inverting HIGH-to-LOW level shifter

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit see Figure 8.

Symbol	Parameter	nmeter Conditions T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit		
			Min	Тур	Max	Min	Max	Min	Max	
C <sub>PD</sub>	power dissipation capacitance	$C_L$ = 50 pF; f = 1 MHz; $V_I$ = GND to $V_{CC}$	-	14	-	-	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .
- [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

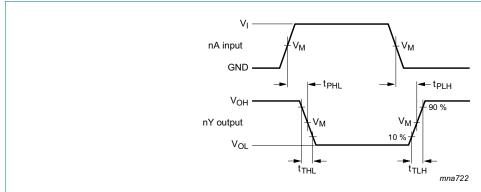
C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

### 11. Waveforms



Measurement points are given in Table 8.

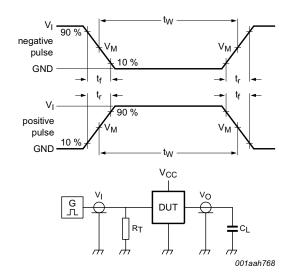
 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Fig 7. The input (nA) to output (nY) propagation delays

#### Table 8. Measurement points

Туре	Input	Output	
	V <sub>M</sub>	V <sub>M</sub>	
74HC4049	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	

#### Hex inverting HIGH-to-LOW level shifter



Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

R<sub>L</sub> = Load resistance.

S1 = Test selection switch.

Fig 8. Test circuit for measuring switching times

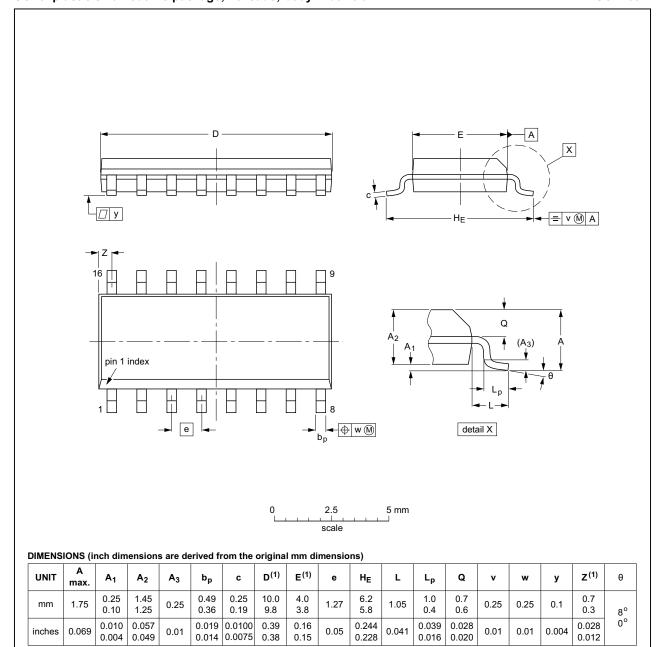
Table 9. Test data

Туре	Input L		Load	Test
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	C <sub>L</sub>	
74HC4049	V <sub>CC</sub>	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

# 12. Package outline

#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



#### Note

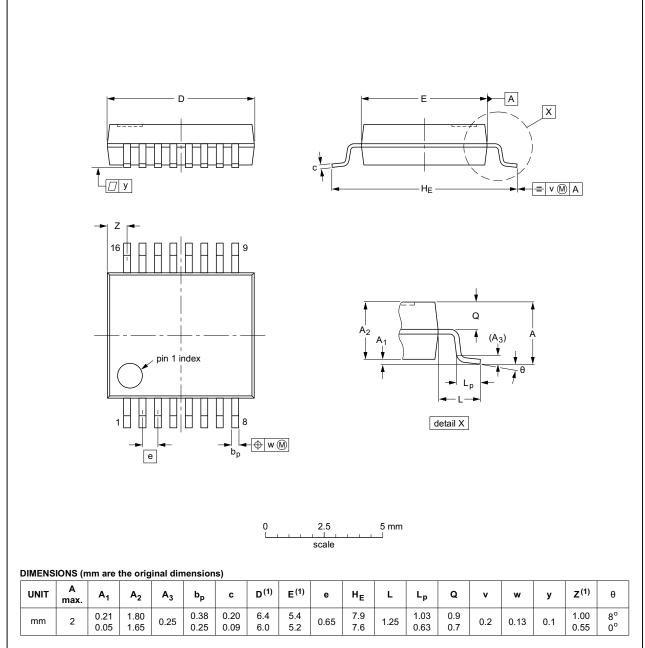
<sup>1.</sup> Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

Fig 9. Package outline SOT109-1 (SO16)

#### SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



#### Note

<sup>1.</sup> Plastic or metal protrusions of 0.25 mm maximum per side are not included.

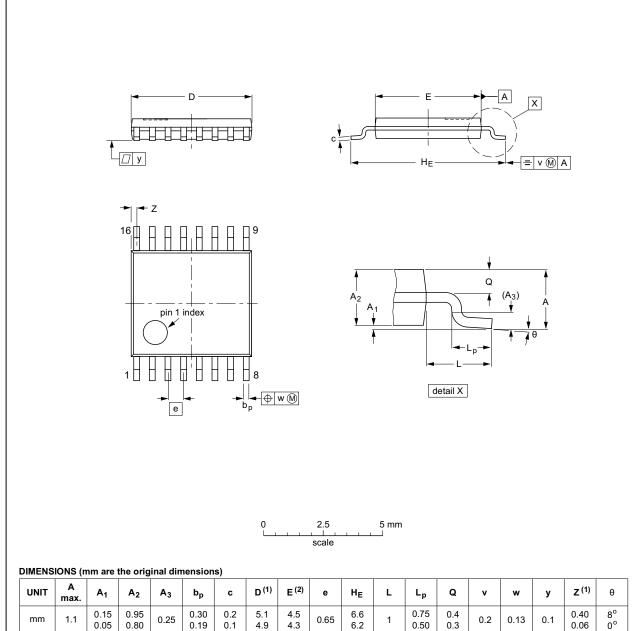
	OUTLINE VERSION		REFER	EUROPEAN	ISSUE DATE		
		IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	SOT338-1		MO-150				<del>99-12-27</del> 03-02-19

Fig 10. Package outline SOT338-1 (SSOP16)

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### TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	>	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	OUTLINE VERSION		REFER	EUROPEAN	ISSUE DATE		
		IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	SOT403-1		MO-153				<del>99-12-27</del> 03-02-18

Fig 11. Package outline SOT403-1 (TSSOP16)

## Hex inverting HIGH-to-LOW level shifter

## 13. Abbreviations

#### Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 14. Revision history

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC4049 v.7	20160205	Product data sheet	-	74HC4049 v.6
Modifications:	Type num	ber 74HC4049N (SOT38-4	1) removed.	
74HC4049 v.6	20130108	Product data sheet	-	74HC4049 v.5
Modifications:	New gene	eral description.	•	'
74HC4049 v.5	20120803	Product data sheet	-	74HC4049 v.4
Modifications:	Measuren	nent points added to figure	7 (errata).	
74HC4049 v.4	20111212	Product data sheet	-	74HC4049 v.3
74HC4049 v.3	20101230	Product data sheet	-	74HC4049_CNV v.2
74HC4049_CNV v.2	19970827	Product specification	-	-

#### Hex inverting HIGH-to-LOW level shifter

## 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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#### Hex inverting HIGH-to-LOW level shifter

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